

(10) **Patent No.:** US 9,472,488 B2
(45) **Date of Patent:** Oct. 18, 2016

- (58) **Field of Classification Search**
CPC H01L 23/473–23/4735; H05K 7/20254;
H05K 7/20927–7/20936
See application file for complete search history.

- (56)
- References Cited**

- U.S. PATENT DOCUMENTS

- | | | | | |
|-----------|-----|--------|--------------|----------------------|
| 4,953,634 | A * | 9/1990 | Nelson | F28F 3/02
165/147 |
| 5,002,123 | A * | 3/1991 | Nelson | F28F 3/02
165/147 |

- (Continued)

- FOREIGN PATENT DOCUMENTS

- | | | | |
|----|-------------|---|---------|
| JP | H06-326226 | A | 11/1994 |
| JP | 2001-035981 | A | 2/2001 |

- (Continued)

- ## OTHER PUBLICATIONS

- Europe Patent Office, “Search Report for EP 13778515.0,” Nov. 24, 2015.

- (Continued)

- PCT Pub. Date:
- Oct. 24, 2013**

- (65) **Prior Publication Data**

- Primary Examiner — Robert J Hoffberg
(74) Attorney, Agent, or Firm — Manabu Kanesaka

- US 2014/0376184 A1 Dec. 25, 2014

- (57) **ABSTRACT**

- (30) **Foreign Application Priority Data**

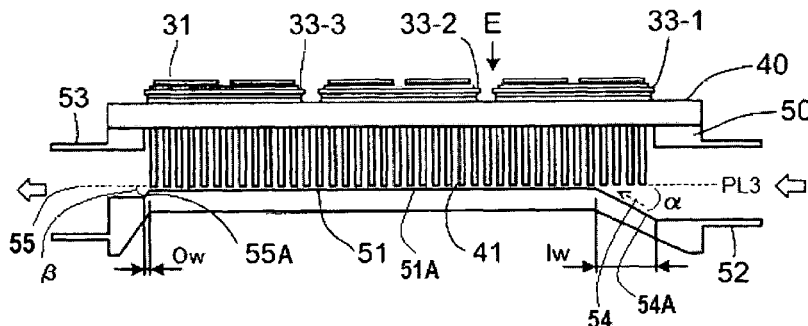
- Apr. 16, 2012 (JP) 2012-092956

- (51) **Int. Cl.**
H05K 7/20 (2006.01)
H01L 23/473 (2006.01)
 (Continued)

- (52) **U.S. Cl.**
CPC *H01L 23/467* (2013.01); *F28F 3/00*
(2013.01); *F28F 9/00* (2013.01); *H01L 23/36*
(2013.01);

- (Continued)

8 Claims, 9 Drawing Sheets



- (51) **Int. Cl.**
H01L 23/467 (2006.01)
F28F 3/00 (2006.01)
F28F 9/00 (2006.01)
H01L 23/36 (2006.01)
H01L 25/07 (2006.01)
H01L 23/373 (2006.01)
H01L 23/00 (2006.01)
- (52) **U.S. Cl.**
CPC **H01L 23/473** (2013.01); **H05K 7/20254**
(2013.01); **H05K 7/20927** (2013.01); **H01L**
23/3735 (2013.01); **H01L 24/32** (2013.01);
H01L 24/48 (2013.01); **H01L 24/73** (2013.01);
H01L 25/072 (2013.01); **H01L 2224/32225**
(2013.01); **H01L 2224/48091** (2013.01); **H01L**
2224/48137 (2013.01); **H01L 2224/73265**
(2013.01); **H01L 2924/1305** (2013.01); **H01L**
2924/13055 (2013.01); **H01L 2924/13091**
(2013.01); **H01L 2924/19107** (2013.01)
- (56) **References Cited**
- U.S. PATENT DOCUMENTS**
- 6,414,867 B2 * 7/2002 Suzuki H02M 7/003
361/709
6,978,856 B2 * 12/2005 Nakamura B60H 1/00392
165/43
7,090,044 B2 * 8/2006 Nakamura B60H 1/00392
180/65.8
7,252,167 B2 * 8/2007 Nakamura B60H 1/00392
180/68.4
7,660,122 B2 * 2/2010 Nakamura B60H 1/00392
165/104.33
7,983,044 B2 * 7/2011 Nakamura B60H 1/00392
165/104.33
- 8,081,465 B2 * 12/2011 Nishiura H01L 23/3735
165/147
8,902,589 B2 * 12/2014 Gohara H01L 23/3735
165/104.19
9,190,344 B2 * 11/2015 Mori H01L 23/473
9,220,182 B2 * 12/2015 Otsuka H05K 7/20236
9,237,676 B2 * 1/2016 Gohara H01L 23/3735
9,238,275 B2 * 1/2016 Yasuda B23K 1/0012
9,245,821 B2 * 1/2016 Gohara H01L 23/3735
9,263,367 B2 * 2/2016 Nakagawa H01L 23/473
2001/0014029 A1 8/2001 Suzuki et al.
2004/0020231 A1 2/2004 Nakamura et al.
2008/0237847 A1 10/2008 Nakanishi et al.
2009/0145581 A1 * 6/2009 Hoffman F28F 1/40
165/80.3
2010/0172091 A1 7/2010 Nishiura
- FOREIGN PATENT DOCUMENTS**
- JP 2001-308246 A 11/2001
JP 2002-093974 A 3/2002
JP 2004-006811 A 1/2004
JP 2004-128439 A 4/2004
JP 2007-081375 A 3/2007
JP 2007-324531 A 12/2007
JP 2008-167650 A 7/2008
JP 2008-251932 A 10/2008
JP 2008-263137 A 10/2008
JP 3152132 U 7/2009
JP 2010-123881 A 6/2010
JP 2010-153785 A 7/2010
WO 2013/118809 A1 8/2013
- OTHER PUBLICATIONS**
- PCT, "International Search Report for International Application No.
PCT/JP2013/060881".
- * cited by examiner

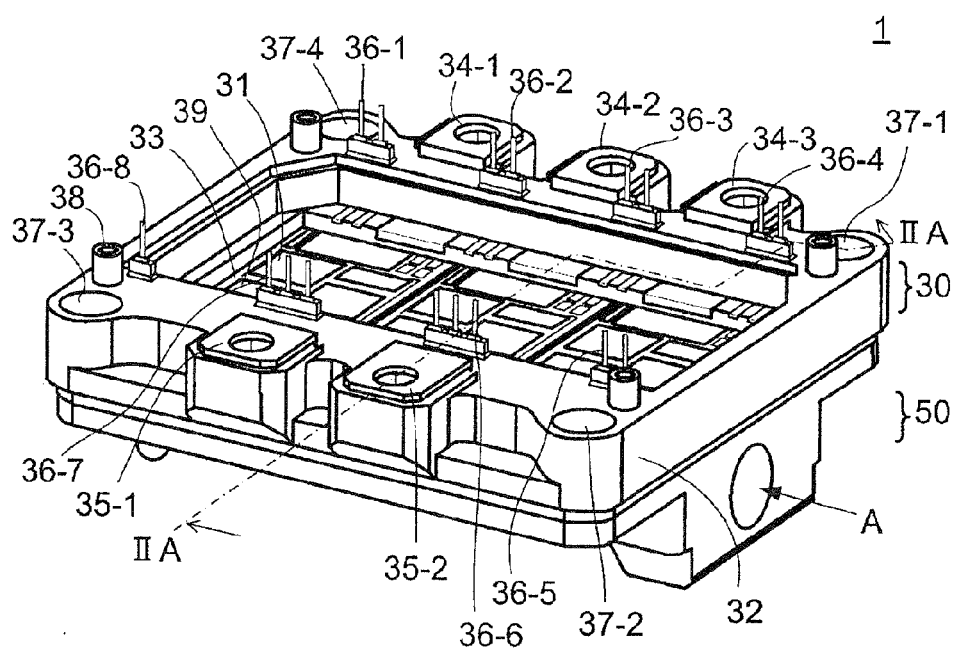
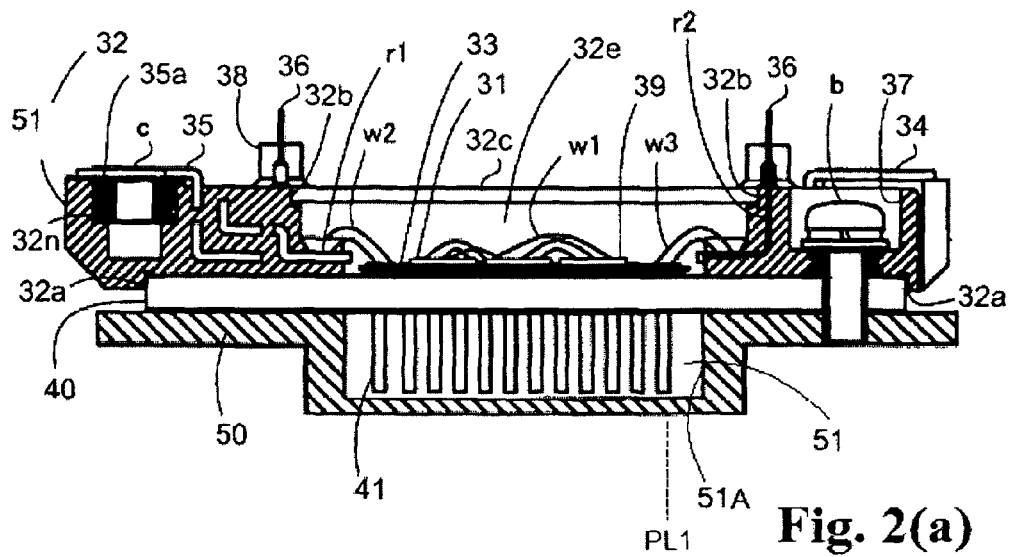


Fig. 1



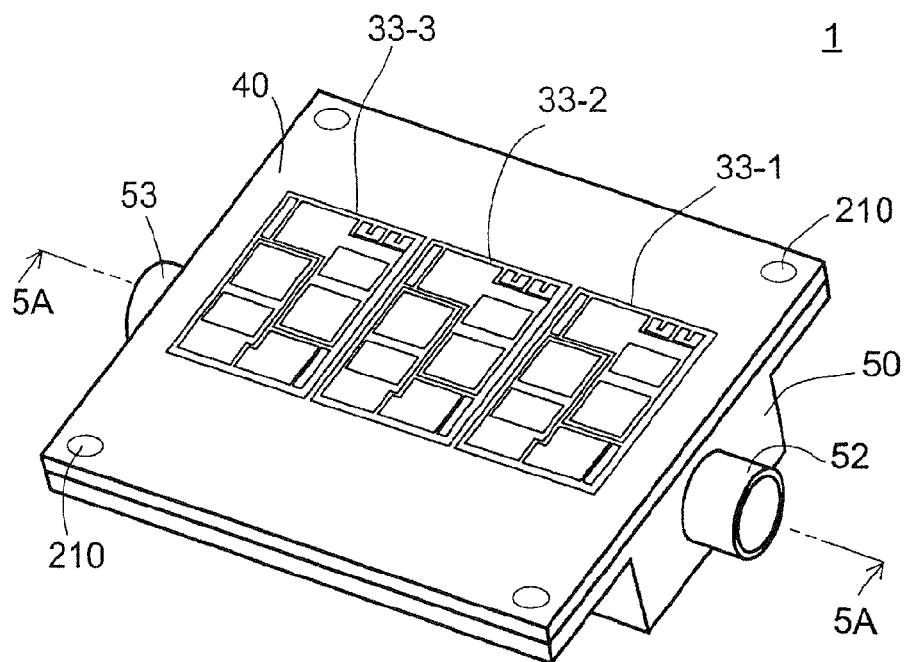


Fig. 3(a)

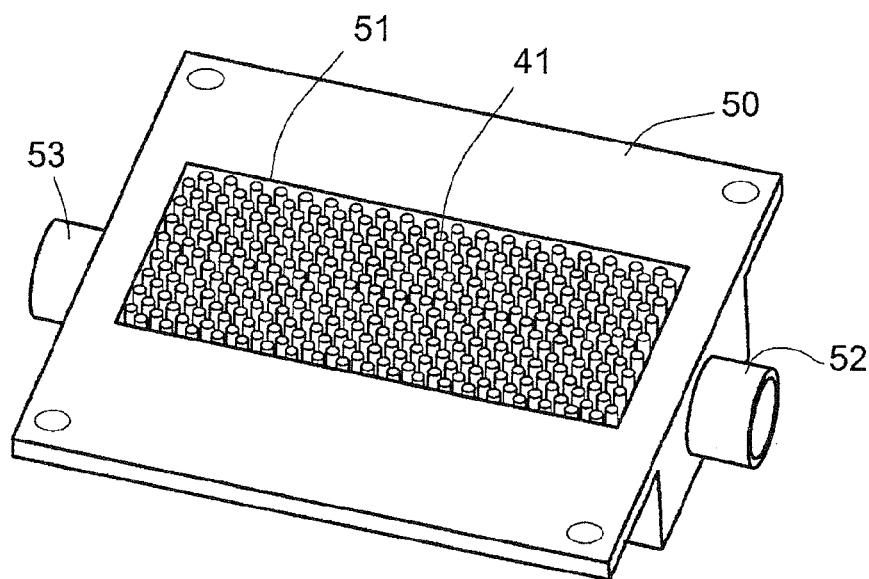


Fig. 3(b)

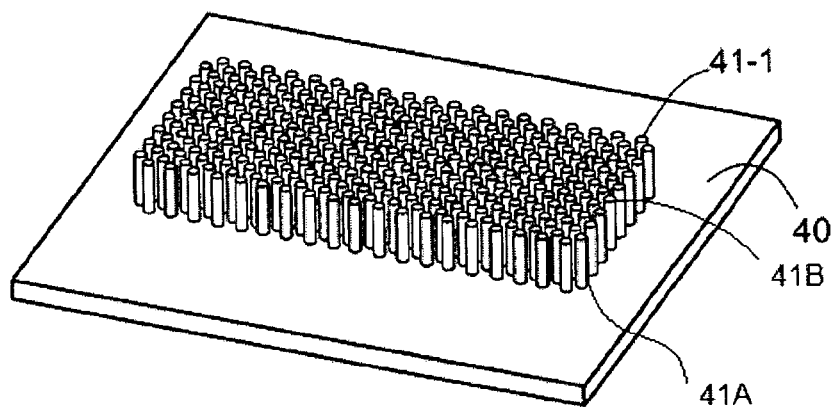


Fig. 4(a)

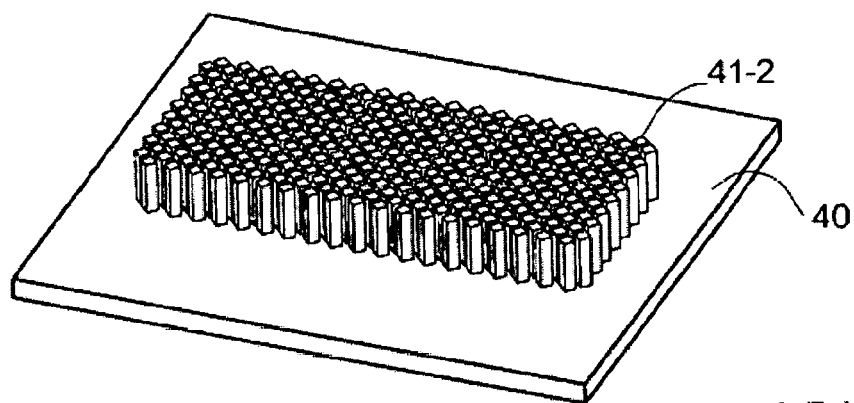


Fig. 4(b)

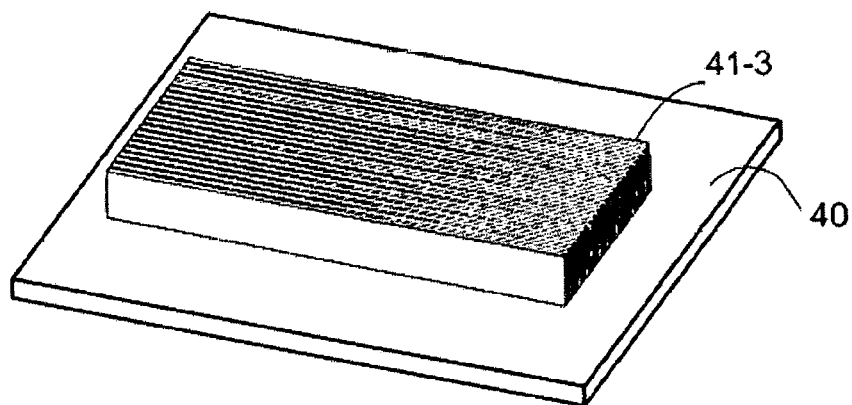
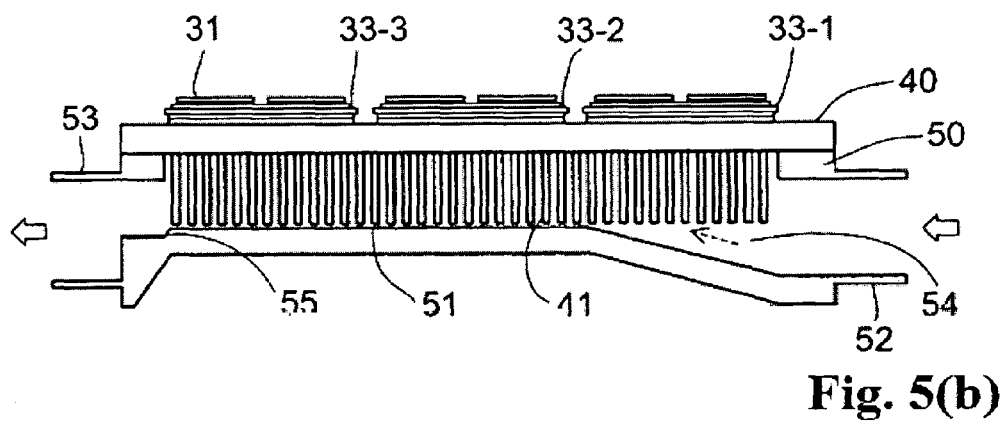
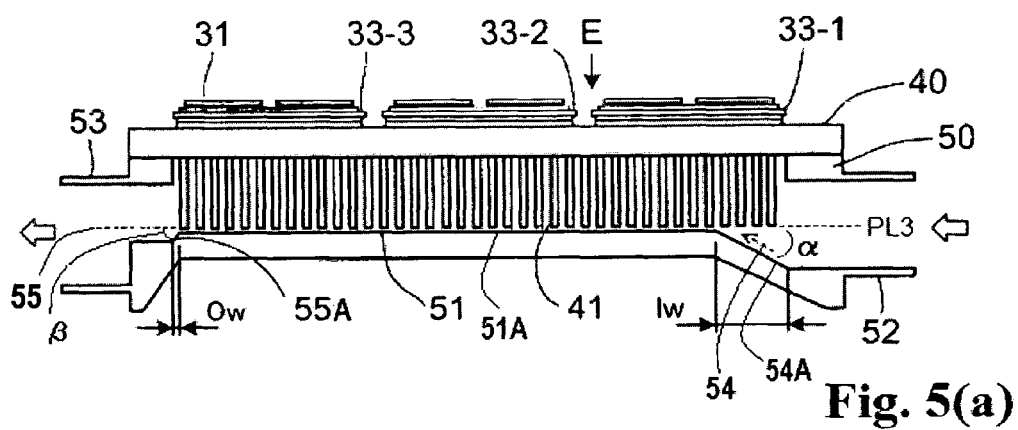
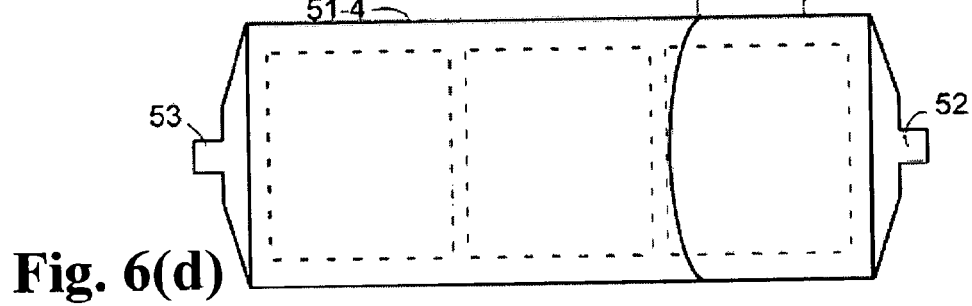
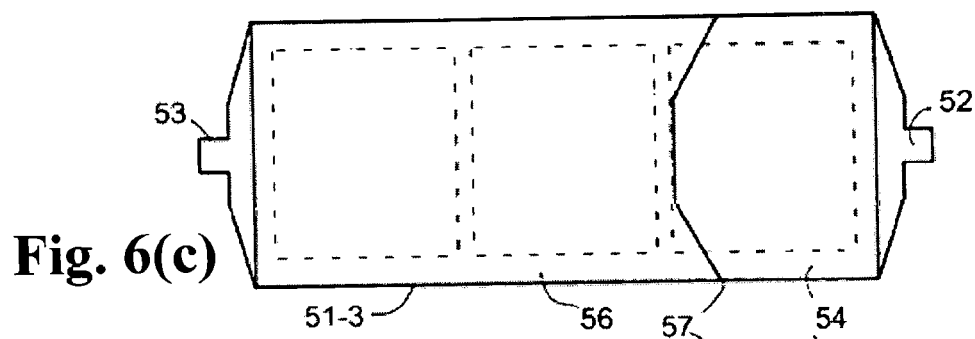
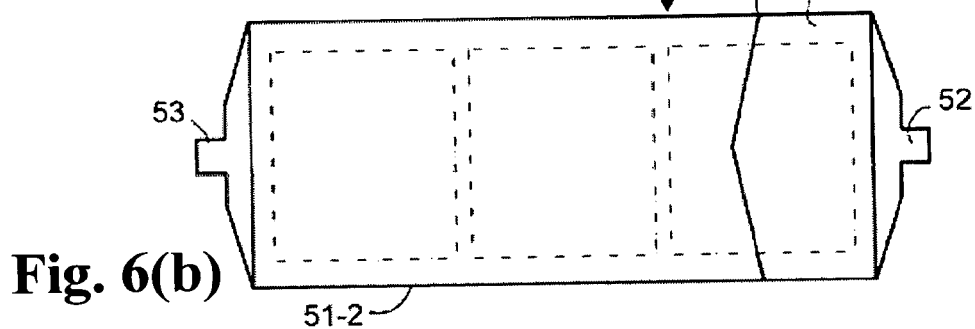
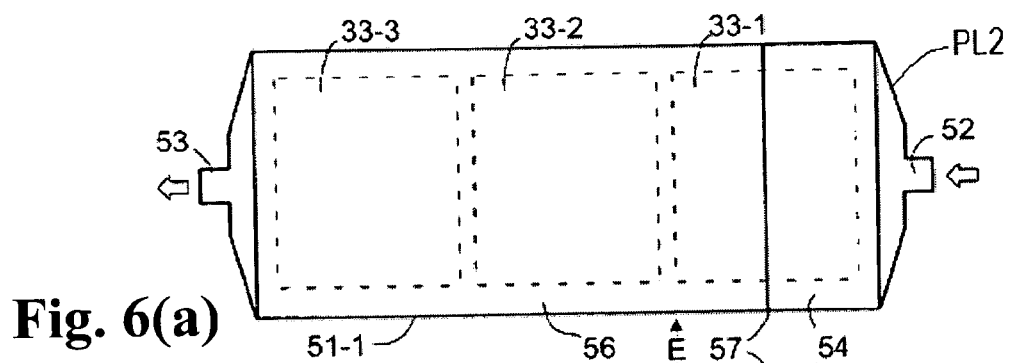


Fig. 4(c)





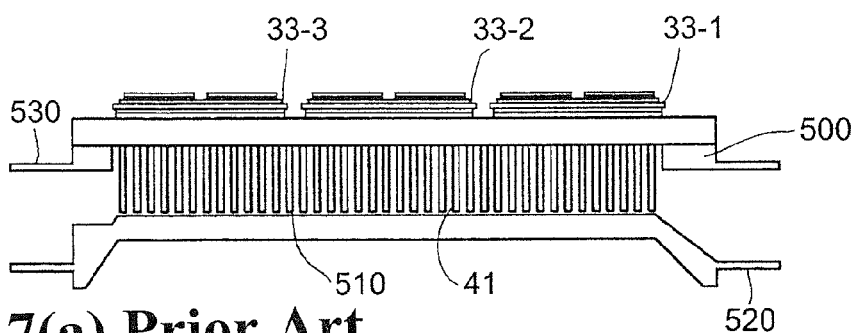


Fig. 7(a) Prior Art

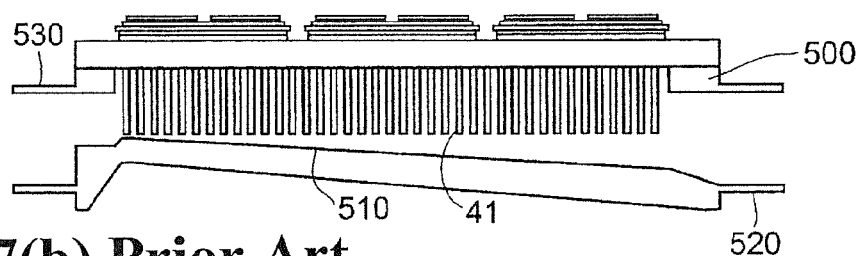


Fig. 7(b) Prior Art

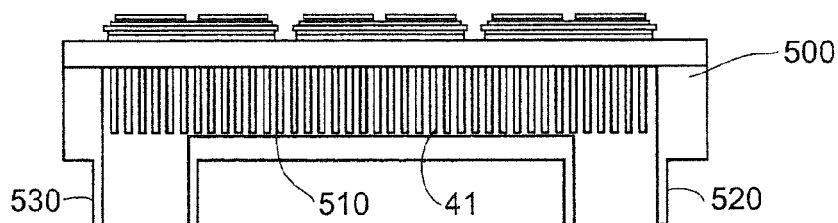


Fig. 7(c) Prior Art

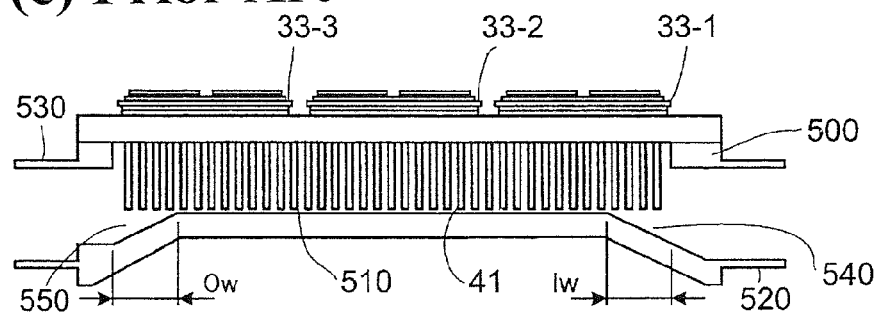


Fig. 7(d) Prior Art

Fig. 8(a)

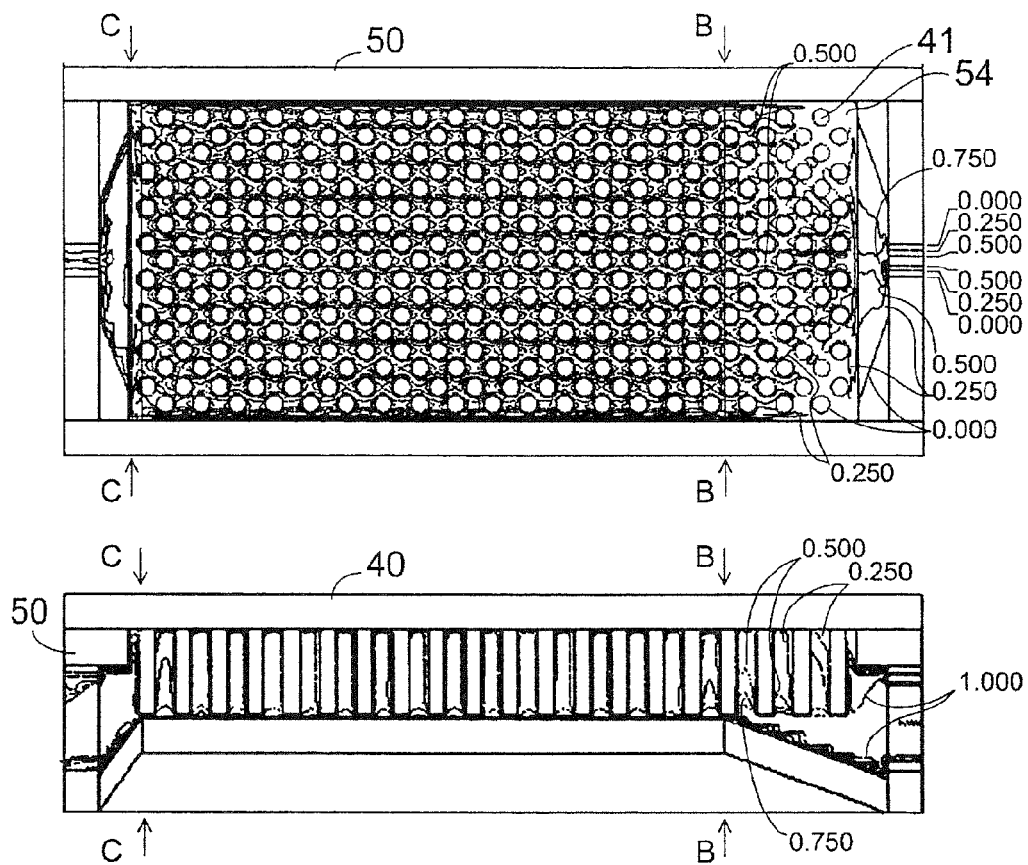
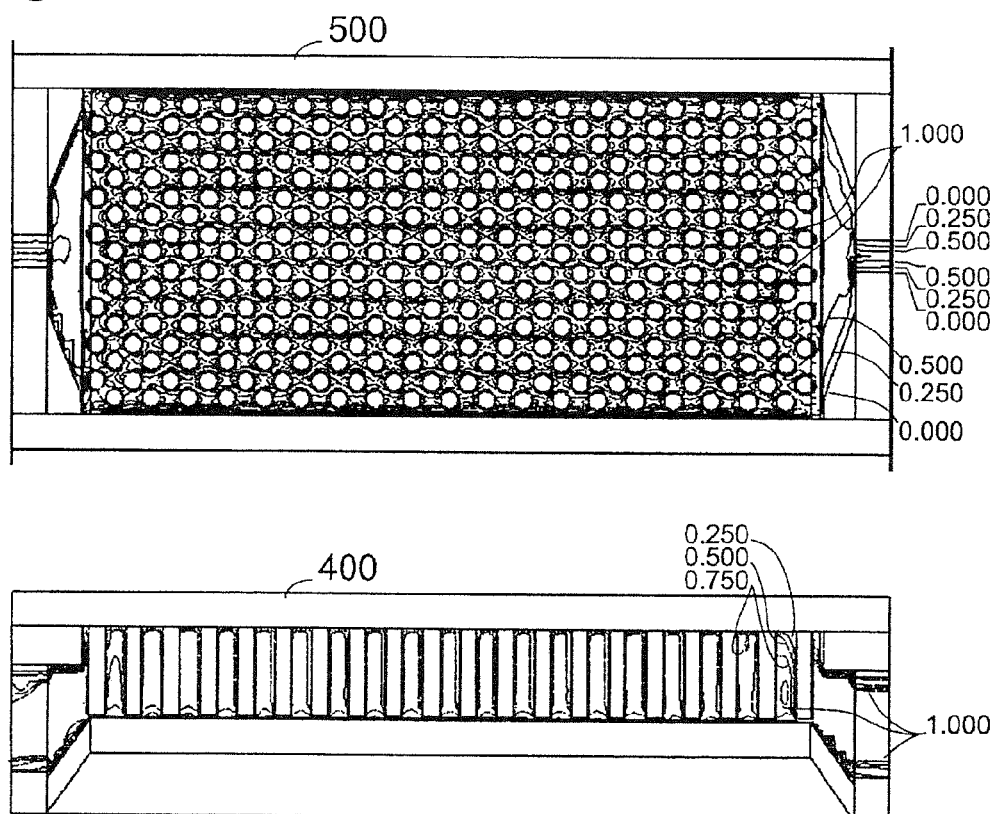


Fig. 8(b)

Fig. 9(a) Prior Art**Fig. 9(b) Prior Art**

1

SEMICONDUCTOR DEVICE AND COOLER THEREOF

RELATED APPLICATIONS

The present application is National Phase of International Application No. PCT/JP2013/060881 filed Apr. 11, 2013, and claims priority from Japanese Application No. 2012-092956 filed Apr. 16, 2012.

TECHNICAL FIELD

The present invention relates to a semiconductor device that has at least a semiconductor module and a cooler, and to the cooler used in this semiconductor device.

BACKGROUND ART

Semiconductor modules with power semiconductor chips are used in the inverters (power converters) of the variable speed drives for the motors of electric vehicles. The elements such as insulated gate bipolar transistors (referred to as "IGBT," hereinafter) are used as the power semiconductor chips. Because the power semiconductor chips generate heat due to high current flowing therein, a semiconductor module is used in combination with a cooler. In electric vehicles and other products with limited weight and space to attach a cooler, a liquid-cooled cooler using a circulatory coolant is used in order to improve the heat dissipation performance of the semiconductor module.

A semiconductor module has a heat dissipation base that is connected thermally to power semiconductor chips via a substrate, and the heat dissipation base is provided with cooling fins. The cooling fins are accommodated in a flow path formed between the heat dissipation base and a cooler. By flowing a pressurized cooling medium (also referred to as "coolant," hereinafter) through the cooling fins, heat generated by the semiconductor chips is efficiently released to the cooling medium. The cooling medium that is warmed up by the heat released from the semiconductor chips is cooled by an external heat exchanger, which is then pressurized by a pump and then returned to the flow path in which the cooling fins are disposed.

This type of conventional technique is disclosed in, for example, Patent Documents 1 to 5.

Patent Document 1 discloses a cooling system that has a cooling unit accommodating fins therein, a partial structure that has a cross-sectional flow path that gradually narrows down in the short-side direction of the cooling unit and gradually expands in the long-side direction of the same, and a partial structure that has a cross-sectional flow path that gradually expands from the short side of the cooling unit and gradually narrows down from the long side of the same. Patent Document 2 discloses a cooler that has a parallel flow path configured by a large number of fine flow paths, a first header for distributing a coolant to each flow path of the parallel flow path, and a second header for merging the coolant flowing out of the parallel flow path. Patent Document 3 discloses a cooling device that has a protrusion disposed on an upper surface of a bottom part that configures a bottom surface of a coolant path, wherein the protrusion is formed by an upstream-side upward inclined surface and a downstream-side downward inclined surface. Patent Document 4 discloses a power module cooling unit in which a bottom surface of an opening of a heat sink is provided with a spacer for smoothly reducing the cross-sectional area of a flow path. Patent Document 5 discloses a semiconductor

2

cooling device in which a flow path cover is formed in such a manner that the clearance between the flow path cover and the edges of the pin-shaped fins is wide on the inlet side and narrow on the outlet side. Patent Document 6 discloses a cooling device in which heat transfer fins are formed in such a manner that a coolant is placed higher on the inlet side than on the outlet side.

Patent Document 1: Japanese Patent Application Publication No. 2004-6811 (FIGS. 1 and 7, paragraphs 0023 to 0031, and 0056 to 0061)

Patent Document 2: Japanese Patent Application Publication No. 2001-35981 (FIGS. 1 and 2, paragraphs 0020 to 28)

Patent Document 3: Japanese Patent Application Publication No. 2008-263137 (FIG. 11, paragraphs 0035 to 0038)

Patent Document 4: Japanese Patent Application Publication No. 2001-308246 (FIG. 9, paragraph 0034)

Patent Document 5: Japanese Patent Application Publication No. 2010-153785 (FIGS. 7 and 8, paragraphs 0035 to 0037)

Patent Document 6: Japanese Patent Application Publication No. 2007-81375 (FIGS. 2, 3, 6, and 7, paragraphs 0038 to 0050)

Incidentally, in the semiconductor devices described above, the cooling fins tend to be designed to have detailed and complicated shapes in order to efficiently release the heat generated by the power semiconductor chips. The use of the cooling fins of such shapes is likely to increase pressure loss in the coolers, creating a need for a high-output pump for circulating the coolant. On the other hand, reducing the sizes of the semiconductor devices or configuring the semiconductor devices to provide high outputs, leads to an increase in the amount of heat generated per unit area, creating a need for detailed, dense cooling fins, which results in an increase of pressure loss and creating a need for a large pump.

DISCLOSURE OF THE INVENTION

In a configuration where a plurality of power semiconductor chips is disposed along the direction in which a coolant flows, it is difficult to cool the chips evenly.

An object of the present invention, therefore, is to solve these problems and to provide a semiconductor device, whether small or high-output, which is capable of not only keeping its cooling performance with low pressure loss without using a large pump, but also evenly cooling a plurality of power semiconductor chips therein, as well as a cooler used in this semiconductor device.

In order to solve the problems described above, a semiconductor device according to a first aspect of the present invention is a semiconductor device that has a semiconductor module and a cooler for cooling a power semiconductor element mounted on a substrate in the semiconductor module. The semiconductor device comprises at least: a heat dissipation base; cooling fins which form a cluster of a plurality of pin members or blade members having an approximately rectangular cuboid contour, and which are provided on a first principal surface of the heat dissipation base; a cooler which is fixed to the heat dissipation base and has a cooling unit accommodating the cooling fins therein and a coolant inlet and a coolant outlet that are formed at respective ends of the cooling unit to face each other in a longitudinal direction; a first substrate which is bonded, in the vicinity of the coolant inlet, to a second principal surface of the heat dissipation base such that the position of the first substrate corresponds to the position of the cooling fins; and

3

a second substrate which is bonded, in the vicinity of the coolant outlet, to the second principal surface of the heat dissipation base.

Furthermore, the cooling unit has: a first header part that has at least a first bottom surface that is inclined toward a bottom plane of the cooling fins so that a coolant supplied from the coolant inlet flows from a side plane and the bottom plane of the cooling fins on the coolant inlet side, into the cooling fins, and toward the coolant outlet; and a second header part that has at least a second bottom surface that is inclined from an end portion of the bottom plane of the cooling fins so that the coolant discharged from the cooling fins flows to the coolant outlet.

With the first header part and the second header part, the semiconductor device of the present invention can not only cool the power semiconductor elements of the first and second substrates substantially evenly, but also reduce pressure loss of the cooler, the first and second substrates being disposed in the longitudinal direction of the cooling unit.

In order to solve the problems described above, a semiconductor device according to a second aspect of the present invention is a semiconductor device that has a semiconductor module and a cooler for cooling a power semiconductor element mounted on a substrate in the semiconductor module. The semiconductor device comprises at least: a heat dissipation base; cooling fins which form a cluster of a plurality of pin members or blade members having an approximately rectangular cuboid contour, and which are provided on a first principal surface of the heat dissipation base; a cooler which is fixed to the heat dissipation base and has a cooling unit accommodating the cooling fins therein and a coolant inlet and a coolant outlet that are formed at respective ends of the cooling unit to face each other in a longitudinal direction; a first substrate which is bonded, in the vicinity of the coolant inlet, to a second principal surface of the heat dissipation base such that the position of the first substrate corresponds to the position of the cooling fins; and a second substrate which is bonded, in the vicinity of the coolant outlet, to the second principal surface of the heat dissipation base.

Furthermore, the cooling unit has: a first header part which has a first bottom surface disposed between the coolant inlet and an end portion of the first substrate on the coolant outlet side and inclined toward a bottom plane of the cooling fins so that a coolant supplied from the coolant inlet flows toward the cooling fins; and a second header part which has a second bottom surface that is inclined from an end portion of the bottom plane of the cooling fins on the coolant outlet side so that the coolant discharged from the cooling fins flows to the coolant outlet.

With the first header part and the second header part, the semiconductor device of the present invention can not only reduce pressure loss generated between the coolant inlet and the end portion of the first substrate on the coolant outlet side, but also allow the coolant to flow smoothly toward the coolant outlet. As a result, the power semiconductor elements mounted in the first substrate and the second substrate can be cooled substantially evenly, reducing the pressure loss of the cooler.

In order to solve the problems described above, a semiconductor device according to a third aspect of the present invention is a semiconductor device that has a semiconductor module and a cooler for cooling a power semiconductor element mounted on a substrate in the semiconductor module. The semiconductor device comprises at least: a heat dissipation base; cooling fins which form a cluster of a plurality of pin members or blade members having an

4

approximately rectangular cuboid contour, and which are provided on a first principal surface of the heat dissipation base; a cooler which is fixed to the heat dissipation base and has a cooling unit accommodating the cooling fins therein and a coolant inlet and a coolant outlet that are formed at respective ends of the cooling unit to face each other in a longitudinal direction; a first substrate which is bonded, in the vicinity of the coolant inlet, to a second principal surface of the heat dissipation base such that the position of the first substrate corresponds to the position of the cooling fins; and a second substrate which is bonded, in the vicinity of the coolant outlet, to the second principal surface of the heat dissipation base.

Furthermore, the cooling unit has: a first header part for supplying a coolant from the coolant inlet toward the cooling fins; and a second header part for discharging the coolant from the cooling fins to the coolant outlet, and the areas of a side plane and a bottom plane of the cooling fins exposed into the first header part are greater than the area of a side plane of the cooling fins exposed to the second header part.

Because the areas of the side plane and bottom plane of the cooling fins exposed into the first header part are greater than the area of the side plane of the cooling fins exposed to the second header part, the semiconductor of the present invention can cool the power semiconductor chips of the cooler between the first header part and the second header part substantially evenly. Therefore, not only is it possible to reduce pressure loss of the cooler, but also the power semiconductor chips mounted in the first substrate on the first header part side and the power semiconductor chips mounted in the second substrate on the second header side can be cooled substantially evenly.

Moreover, in order to solve the problems described above, a cooler according to a fourth aspect of the present invention is a cooler for cooling a semiconductor module, which has at least: a heat dissipation base; at least two substrates bonded parallel to each other on the heat dissipation base; a power semiconductor element mounted on each of the substrates; and cooling fins which form a cluster of a plurality of pin members or blade members having an approximately rectangular cuboid contour, and which are provided on the heat dissipation base, the cooler having: a cooling unit accommodating the cooling fins therein; and a coolant inlet and a coolant outlet that are formed at respective ends of the cooling unit to face each other in a longitudinal direction.

Furthermore, the cooling unit has: a first header part which has at least a first bottom surface that is inclined toward a bottom plane of the cooling fins so that a coolant supplied from the coolant inlet flows from a side plane and the bottom plane of the cooling fins on the coolant inlet side, into the cooling fins, and toward the coolant outlet; and a second header part which has at least a second bottom surface that is inclined from an end portion of the bottom plane of the cooling fins so that the coolant discharged from the cooling fins flows to the coolant outlet. The cooler is used by being fixed to the heat dissipation base.

With the first header part and the second header part, the cooler of the present invention can not only cool the power semiconductor elements of the first and second substrates substantially evenly, but also reduce pressure loss of the cooler main body, the first and second substrates being disposed in the longitudinal direction of the cooling unit.

The first to third aspects of the present invention can provide a semiconductor device that is capable of not only cooling the power semiconductor elements of at least two

substrates substantially evenly, but also reducing power loss of a cooler of the semiconductor device.

The fourth aspect of the present invention can provide a cooler that is capable of not only cooling the power semiconductor elements of at least two substrates substantially evenly, but also reducing power loss of the cooler main body.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a perspective view of a semiconductor device according to an embodiment of the present invention;

FIG. 2(a) is a cross-sectional side view of the semiconductor device according to the embodiment of the present invention, taken along the arrow IIA-IIA and viewed from A-side shown in FIG. 1, and FIG. 2(b) shows a modification of FIG. 2(a);

FIGS. 3(a) and 3(b) are perspective views, schematically showing the principal parts of the semiconductor device according to the embodiment of the present invention, wherein FIG. 3(a) is a diagram showing a substrate, a heat dissipation base, and a cooler, and FIG. 3(b) is a diagram showing cooling fins and the cooler;

FIGS. 4(a)-4(c) are perspective views showing the heat dissipation base according to the embodiment of the present invention, wherein FIG. 4(a) is a diagram showing a first modification of the cooling fins, FIG. 4(b) is a diagram showing a second modification of the cooling fins, and FIG. 4(c) is a diagram showing a third modification of the cooling fins;

FIGS. 5(a) and 5(b) are cross-sectional diagrams of the semiconductor device according to the embodiment of the present invention, taken along the arrow 5A-5A shown in FIG. 3(a), wherein FIG. 5(a) is a diagram showing a first modification of the cooler, and FIG. 5(b) is a diagram showing a second modification of the cooler;

FIGS. 6(a)-6(d) are plan views showing the cooler according to the embodiment of the present invention, wherein FIG. 6(a) is a diagram showing a first modification, FIG. 6(b) is a diagram showing a second modification, FIG. 6(c) is a diagram showing a third modification, and FIG. 6(d) is a diagram showing a fourth modification;

FIGS. 7(a)-7(d) are cross-sectional diagrams showing the principal parts of a conventional semiconductor device;

FIGS. 8(a) and 8(b) are contour diagrams showing a distribution of flow velocities of a coolant in the semiconductor device according to the embodiment of the present invention, wherein FIG. 8(a) is a plan view and FIG. 8(b) is a side view; and

FIGS. 9(a) and 9(b) are contour diagrams showing a distribution of flow velocities of a coolant in the conventional semiconductor device, wherein FIG. 9(a) is a plan view and FIG. 9(b) is a side view.

BEST MODE FOR CARRYING OUT THE INVENTION

Preferred embodiments of a semiconductor device according to the present invention and a cooler used in this semiconductor device are described hereinafter with reference to the accompanying drawings. The accompanying drawings are provided for the purpose of illustrating the embodiment of the present invention specifically. The terms indicating such directions as "upper," "lower," "bottom," "front," and "back" are used with reference to the directions illustrated in the accompanying drawings.

FIG. 1 is a perspective view of a semiconductor device according to an embodiment of the present invention. FIG. 2(a) is a cross-sectional side view of the semiconductor device, taken along the arrow IIA-IIA and viewed from A-side shown in FIG. 1.

As shown in FIGS. 1 and 2(a), a semiconductor device 1 has a semiconductor module 30 equipped with power semiconductor chips 31, and a cooler 50 for cooling the power semiconductor chips 31.

The semiconductor module 30 has at least a surrounding case 32 and an insulating substrate 33 to which the power semiconductor chips 31 are bonded.

The surrounding case 32 is an O-shaped or frame-shaped resin case that has an approximately rectangular cuboid contour. The surrounding case 32 is internally provided with three insulating substrates 33. The resin is, for example, polyphenylene sulfide. One of the sides of the frame portion of the surrounding case 32 is provided with a main terminal (U) 34-1, a main terminal (V) 34-2, and a main terminal (W) 34-3, and another side of the frame portion is provided with a power supply terminal (P) 35-1 and a power supply terminal (N) 35-2. The main terminal (U) 34-1, the main terminal (V) 34-2, and the main terminal (W) 34-3 are terminals for driving, for example, an external motor by performing switching control of the power semiconductor chips 31. The power supply terminal (P) 35-1 and the power supply terminal (N) 35-2 are terminals supplied with power from the outside.

As shown in FIG. 2(a), the power supply terminal 35 is provided with an open hole 35a. A screw, not shown, is inserted into the open hole 35a and then fastened to a nut 32n disposed in the surrounding case 32. The power supply terminal 35 is installed on the front surface of the surrounding case 32 in the bent form. These terminals are provided to the surrounding case 32 by means of, for example, insert molding.

Control terminals 36-1 to 36-8 are relay terminals for connecting the gate electrodes of the power semiconductor chips 31 of the surrounding case 32 to a control circuit on a circuit board, not shown, and performing the switching control of the power semiconductor chips 31 in response to a control signal transmitted from the control circuit. The four corners of the frame of the surrounding case 32 are provided with openings 37-1 to 37-4. Screws b are inserted into these openings 37-1 to 37-4 to tightly fix the semiconductor module 30 and the cooler 50 to each other. The surrounding case 32 is also provided with screw seats 38 for the purpose of attaching the circuit board (not shown) to an upper surface of the surrounding case 32.

The insulating substrates 33 are each formed by bonding a plate-like circuit pattern made of copper, copper alloy or the like to either surface of a ceramic or resin insulating plate. Each of the insulating substrates 33 is mounted with a power semiconductor chip 31 such as an IGBT or MOSFET, and an FWD 39 (Free Wheeling Diode) which is a diode for commutating a load current. The plurality of power semiconductor elements 31 and FWDs 39 are connected to each other by a bonding wire w1. In each of the insulating substrates 33, the power semiconductor chip 31 and the FWD 39 are connected antiparallel to each other, for example, by a bonding wire, not shown, in addition to the bonding wire w1, and are electrically connected so as to form upper and lower arms.

Furthermore, lead terminals r1, r2 are insert-molded in the frame portion of the surrounding case 32 and connected to the power semiconductor chips 31 and the like by bonding wires w2, w3. Each power semiconductor chip 31 is elec-

trically connected to the motor driving main terminal **34** by a bonding wire, not shown, via the lead terminal, etc. The gate of each power semiconductor chip **31** is connected to the lead terminal **r2** by the bonding wire **w3**, and the lead terminal **r2** is connected to the control terminal **36**.

As shown in FIG. **2(a)**, the openings on the bottom surface side of the surrounding case **32** have a heat dissipation base that is adhered to opening stepped surfaces **32a** by an adhesive to close the openings. The heat dissipation base has a heat dissipation base plate **40** and cooling fins **41**. The heat dissipation base plate **40** is formed from a plate-like member made of or plated with copper, copper alloy, aluminum or aluminum alloy. The cooling fins **41** are formed on the lower surface of the heat dissipation base plate **40** by a known method, for the purpose of cooling the heat dissipation base plate **40** and the power semiconductor chips **31**. Each insulating substrate **33** and the power semiconductor chips **31** thereof are bonded sequentially in this order to the upper surface of the heat dissipation base. Such a semiconductor module in which the insulating substrates **33** are bonded to the heat dissipation base is called "direct water-cooled semiconductor module" and is used mainly in a water-cooled semiconductor device that uses water, long life coolant (LLC), or other form of liquid as a coolant. In the direct water-cooled semiconductor module, cooling efficiency thereof can be improved by arranging the shapes and positions of the power semiconductor chips **31**, the cooling fins **41**, and a cooling unit **51**, reducing the load on a pump used for circulating the coolant. In addition, the flow rate of the coolant can be made higher than that in a conventional semiconductor module, improving the properties and reliability of the semiconductor device.

FIG. **2(b)** shows a modification of the heat dissipation base and the semiconductor device **1** using the same. In this modification, the heat dissipation base has at least the heat dissipation base plate **40**, a base plate **40-1**, and cooling fins **41-1**. The heat dissipation base plate **40** is adhered to the bottom surface of the surrounding case **32**. The heat dissipation base plate **40** is not provided with any cooling fins, but the base plate **40-1** having the cooling fins **41-1** implanted therein is tightly fixed to the heat dissipation base plate **40** via a thermal compound or the like. The semiconductor module with this heat dissipation base is used mainly in an air-cooled semiconductor device that uses air or other form of gas as a coolant.

The insulating substrates **33** are soldered or bonded by sintered metal or the like to the upper surface of the heat dissipation base plate **40**.

An internal space of the surrounding case **32** is filled with a sealing member **32e** made of silicone gel, silicone resin, or epoxy resin. A resin lid plate **32c** is tightly adhered to opening stepped surfaces **32b** of the surrounding case **32** by an adhesive, not shown, to close the surrounding case **32**. Moreover, each opening **37** is provided for the purpose of fixing the surrounding case **32** to the cooler and the like by bolts, as will be described later.

The semiconductor device **1** is used, with the circuit board, not shown, being attached to the screw seats **38** of the surrounding case **32**. The front surface of the circuit board is mounted with a control circuit configured by various circuit elements such as an IC (Integrated Circuit), an LSI (Large Scale Integration), a transistor, a resistor, and a capacitor. Note that the semiconductor device **1** does not need to have the circuit board therein and therefore may be configured in such a manner as to be controlled while connected to external equipment provided with the same functions.

FIGS. **3(a)** and **3(b)** are perspective views, schematically showing the principal parts of the semiconductor device according to the embodiment of the present invention, wherein FIG. **3(a)** is a diagram showing an arrangement of the insulating substrates **33**, the heat dissipation base, and the cooler **50**, and FIG. **3(b)** is a diagram showing an arrangement of the cooling fins **41** of the heat dissipation base and the cooler **50**.

The cooler **50** is tightly fixed to the semiconductor module **30** by screws and bolts via a sealing member, as described above, for example. The cooler **50** is molded from a known material, such as aluminum or aluminum alloy.

As shown in FIGS. **3(a)** and **3(b)**, the cooler **50** has the cooling unit **51** accommodating the cooling fins **41** therein, and a coolant inlet **52** and a coolant outlet **53**, which are configured to communicate with the cooling unit **51**. The cooling unit **51** is an approximately rectangular cuboid concave portion provided in the box-shaped cooler **50**, and looks roughly like a rectangle as viewed in plan. The coolant inlet **52** and the coolant outlet **53** are formed in such a manner that the centers of the openings thereof are located on the surfaces on the narrow sides of the cooling unit **51**, i.e., approximately in the central parts of the two side surfaces of the cooling unit **51** that face each other in the longitudinal direction. The openings are in, for example, a circular or oval shape. The direction in which the coolant is supplied from the coolant inlet **52** and the direction in which the coolant is discharged from the coolant outlet **53** are roughly parallel to the longitudinal direction of the cooling unit **51**.

Connected to the cooler **50** is a pump, not shown, to supply the coolant from the coolant inlet **52** on the upstream side to the cooling unit **51** and to discharge the coolant from the coolant outlet **53** on the downstream side, creating a cooling system in which the coolant circulates.

At least two of the insulating substrates **33** are bonded onto the heat dissipation base in such a manner that these insulating substrates **33** are arranged sequentially from the coolant inlet **52** side along the longitudinal direction of the cooling unit **51**. In FIG. **3(a)**, three insulating substrates **33-1**, **33-2**, **33-3** in the same contour and size are disposed adjacent to each other from the coolant inlet **52** to the coolant outlet **53**.

The cooling fins **41** are formed on the surface that faces the surface of the heat dissipation base plate **40** to which the insulating substrates **33-1**, **33-2**, **33-3** are bonded. The cooling fins **41** are preferably disposed on a surface immediately below the insulating substrates **33-1**, **33-2**, **33-3**, with a short distance therebetween and hence a low thermal resistance, in such a manner that heat generated by the power semiconductor chips **31** is released efficiently. Because the heat that is generated from the power semiconductor chips **31** spreads in the in-plane direction, the heat dissipation base is preferably configured in such a manner that the area of the surface of the heat dissipation base plate **40** to which the cooling fins **41** are adhered is greater than the total area of the insulating substrates **33-1**, **33-2**, **33-3**. It is also preferred that the cooler **50** be configured in such a manner that a constant gap is formed between the cooling unit **51** and the cooling fins **41**. The insulating substrates **33-1**, **33-2**, **33-3** are disposed so as not to be higher than the side walls of the cooling unit **51**. In other words, the insulating substrates **33-1**, **33-2**, **33-3** are disposed in such a manner as to face a coolant flow path configured by the cooling unit **51**.

The cooling fins **41** are formed of a plurality of pin members or blade members that has an approximately

rectangular cuboid contour. The cooling fins **41** are made of copper, copper alloy, aluminum, aluminum alloy, or other known materials and formed on the dissipation base plate **40** by a known method of integral molding, carving, implantation, or the like. The length of the edges of the fins or blades measured from the principal surface of the heat dissipation base plate **40** is preferably 6 mm to 10 mm. The cooling fins **41** can be in any shapes including the known shapes. In view of achieving uniform cooling performance, it is desired that the height of the pins or the like be made even and that each of cooling fin **41** have approximately a rectangular cuboid contour so that the virtual plane obtained by connecting the edges thereof becomes substantially parallel to the surface of the heat dissipation base plate **40**.

It is preferred that the inner diameters of the openings of the coolant inlet **52** and the coolant outlet **53** be equal to or greater than the length of the cooling fins **41** in order to keep the cooling performance and reduce pressure loss of the entire cooling system. For example, when the length of the pins is 10 mm, pressure loss can be reduced by setting the inner diameters at 10 mm or longer. From the perspective of the cooling performance, it is also preferred that the openings be in an oval shape where the short diameter is equal to or longer than the length of the cooling fins **41** and the long diameter is approximately equivalent to the width of the region where the power semiconductor chips **31** are disposed, so that the coolant spreads over the heat generating portion.

FIGS. **4(a)**-**4(c)** are perspective views illustrating the heat dissipation base according to the embodiment of the present invention, wherein FIG. **4(a)** shows a first modification of the cooling fins, FIG. **4(b)** shows a second modification of the cooling fins, and FIG. **4(c)** shows a third modification of the cooling fins. FIG. **4(a)** shows an example in which round pins are used as the cooling fins **41-1** (each pin **41** includes a side surface **41A**, and a bottom surface **41B**), FIG. **4(b)** shows an example in which square pins are used as cooling fins **41-2**, and FIG. **4(c)** shows an example in which blades are used as cooling fins **41-3**. When using the pins as the cooling fins, it is preferred that the pins be staggered 45° to the longitudinal direction in order to inhibit abnormal flows of the coolant and improve the cooling efficiency.

FIGS. **5(a)** and **5(b)** are cross-sectional diagrams of the principal parts of the semiconductor device **1** according to the embodiment of the present invention, taken along the arrow **5A-5A** shown in FIG. **3(a)**, wherein FIGS. **5(a)** and **5(b)** show first and second modifications of the cooler **50**, respectively. The white arrows in each diagram indicate a direction of the flow of the coolant. FIGS. **6(a)**-**6(d)** are plan views showing the coolant flow path in the cooler according to the embodiment of the present invention, viewed from the heat dissipation base side, wherein FIGS. **6(a)** to **6(d)** show first, second, third and fourth modifications of the cooling unit **51**, respectively. The two-dot chain lines indicate the positions of the insulating substrates **33-1**, **33-2**, **33-3**.

In the cooler **50**, the cooling unit **51** accommodating the cooling fins **41** therein has a first header part **54** on the coolant inlet **52** side and a second header part **55** on the coolant outlet **53** side.

The first header part **54** has an enlarged portion with a gradually increasing cross-sectional area, which has a side wall **PL2** (FIG. **6(a)**) that is inclined in such a manner that the coolant introduced from the coolant inlet **52** into the cooler **50** spreads evenly toward a side plane **PL1** (FIG. **2(a)**) of the cooling fins **41**, and a reduced portion with a gradually reducing cross-sectional area, which accommodates the end portions on one side of the cooling fins **41**

therein and has an inclined surface, i.e. first flow surface **54A** (FIG. **5(a)**), for sending the coolant into the cooling fins **41**.

The bottom surface of the reduced portion of the first header part **54** is inclined at an angle α (FIG. **5(a)**) toward the bottom plane **PL3** (FIG. **5(a)**) of the cooling fins **41**, i.e., the virtual plane obtained by connecting the edges of the pins or blades. The inclination is formed anywhere between a part of the first header part **54** on the coolant inlet **52** side and an end portion of the insulating substrate **33-1** on the coolant outlet **53** side (the position E shown in FIGS. **5(a)** and **6(a)**). For the purpose of achieving uniform cooling performance, it is preferred that the inclination be formed anywhere between the center of the insulating substrate **33-1** and the end portion thereof on the coolant outlet **53**.

Owing to such a configuration of the first header part **54**, the coolant flows through the cooling fins **41** obliquely from not only the side plane of the cooling fins **41** but also the edges of the pins configuring the cooling fins **41**, toward the coolant outlet **53**, in the direction shown by the dashed arrow shown in FIGS. **5(a)** and **5(b)**. Pressure loss can be reduced by increasing the area of the cooling fins **41** exposed into the first header part **54**, which is viewed from the coolant supplied from the coolant inlet **52**. Pressure loss occurring in the first header part **54** can be limited to a required level by setting the end of the inclined bottom surface within the range described above.

The second header part **55** has an enlarged portion with a gradually increasing cross-sectional area, which has an inclined surface for discharging the coolant from the cooling fins **41** toward the coolant outlet **53**, and a reduced portion with a gradually reducing cross-sectional area, which has a side wall that is inclined in such a manner as to cause the coolant to flow from a side plane of the cooling fins **41** to gather at the coolant outlet **53**.

The bottom surface of the enlarged portion of the second header part **55** is inclined at a position of an end portion of the bottom plane of the cooling fins **41** on the coolant outlet **53** side. The angle (acute angle β) formed by the bottom surface **55A** (FIG. **5(a)**) of the second header part **55** and the bottom plane of the cooling fins **41** is larger than the angle α formed by the bottom surface of the first header part **54** and the bottom plane of the cooling fins **41**.

The bottom plane **51A** (FIG. **5(a)**) of the cooling unit **51** between the first header part **54** and the second header part **55** is stretched out between the bottom surface of the first header part **54** and the bottom surface of the second header part **55** and is substantially parallel to the bottom plane of the cooling fins **41**. The narrower the gap between this substantially parallel region of the cooling unit **51** and the bottom plane of the cooling fins **41**, the greater the cooling performance can be. It is preferred that the gap be, for example, 0.2 mm to 0.8 mm in view of thermal distortion and the like of the heat dissipation base.

Providing a predetermined gap between the cooling unit **51** and the cooling fins **41** in this manner can allow the coolant to flow through the cooling fins **41** immediately below the insulating substrates **33-2** and **33-3** disposed on the downstream side of the insulating substrate **33-1**, achieving sufficiently high cooling efficiency.

The shapes of the first header part **54** and the second header part **55** are asymmetric with respect to the cooling unit **51**, wherein the volume of the first header part **54** is greater than that of the second header part **55** and the areas of the side plane and bottom plane of the cooling fins **41** on the coolant inlet **52** side that are exposed into the first header part **54** are greater than the area of the side plane of the

11

cooling fins **41** on the coolant outlet **53** side that are exposed into the second header part **55**.

Because the first semiconductor device **1** has the first header part **54**, the cooling unit **51**, and the second header part **55**, a sufficiently low-temperature coolant can be supplied even to the cooling fins **41** immediately below the insulating substrates **33-2** and **33-3** to efficiently cool the power semiconductor chips **31** mounted in the cooler **50** between the first header part **54** and the second header part **55**. Therefore, the power semiconductor chips **31** mounted in the three insulating substrates can be cooled evenly. Even when a pump of the same performance is used, the maximum temperature of the power semiconductor chips **31** can be made lower than that of the prior art, resulting in providing the semiconductor device **1** of excellent cooling performance. The effects described above can be obtained favorably by making the area of the bottom plane of the cooling fins **41** exposed into the first header part **54** greater than the area of the side plane of the cooling fins **41** exposed into the first header part **54**.

The shape of the bottom surface of the first header part **54** can be changed in a various manner, as shown in FIGS. **6(a)** to **6(d)**.

FIG. **6(a)** shows an example of a boundary **57** that appears as a straight top portion (an intersection in the shape of a letter "I") between the bottom surface of the first header part **54** and a surface **56** substantially parallel to the bottom plane of the cooling fins **41**. The surface **56**, substantially parallel to the bottom plane of the cooling fins **41**, is positioned between the bottom surface of the first header part **54** and the bottom surface of the second header part **55** and is stretched out thereto. FIGS. **6(b)** to **6(d)** each illustrate an example in which the center of the boundary **57** in FIG. **6(a)** is curved into a C-shape toward the coolant outlet **53**. In all of these examples, the boundary **57** is located in a section corresponding to the region between center of the insulating substrate **33-1** and its end portion on the coolant outlet **53**, i.e., immediately below the region, the insulating substrate **33-1** being shown by a two-dot chain line in the vicinity of the coolant inlet **52**. Because the downstream-side end portion of the first header part **54** is curved into a convex C-shape toward the downstream side as shown in FIGS. **6(b)** to **6(d)**, the cooling efficiency in the width direction of the cooling unit **51** can be made further uniform.

The semiconductor device **1** and the cooler **50** described above can be produced by a conventionally known method.

FIGS. **7(a)**-**7(d)** are cross-sectional diagrams showing the principal parts of a conventional semiconductor device. Note, in FIGS. **7(a)**-**7(d)**, that the same reference numerals are used to indicate the components that are the same as those illustrated in FIGS. **1** to **6(d)**, and therefore, the descriptions thereof are omitted accordingly.

The conventional semiconductor device shown in FIGS. **7(a)**-**7(d)** are different from the semiconductor device **1** according to the embodiment of the present invention that is described with reference to FIGS. **5(a)** and **5(b)**, in terms of the following features.

For instance, in the semiconductor device shown in FIG. **7(a)**, a cooling unit **510** of a cooler **500** does not have the space corresponding to the first header part **54** of the embodiment of present invention. In the semiconductor device shown in FIG. **7(b)**, on the other hand, the cooling unit **510** does not have the surface **56** parallel to the bottom plane of the cooling fins **41**, which is located between the first and second header parts **54** and **55** of the embodiment of the present invention. In the semiconductor device shown in FIG. **7(c)**, the cooling unit **510** does not have the spaces

12

corresponding to the first and second header parts **54** and **55** of the embodiment of the present invention, and a coolant inlet **520** and a coolant outlet **530** are attached to the bottom portion of the cooling unit **510**, unlike the configuration described in the embodiment of the present invention. In the semiconductor device shown in FIG. **7(d)**, the cooling unit **510** of the cooler **500** has a first header part **540** on the coolant inlet **520** side and a second header part **550** of the same shape and size on the coolant outlet **530** side in such a manner as to be symmetric to the first header part **540**. The length l_w of the inclined region of the bottom surface of the first header part **540** is approximately equal to the length l_o of the inclined region of the bottom surface of the second header part **550**.

FIGS. **8(a)** and **8(b)** are contour diagrams showing a numerically calculated distribution of flow velocities of the coolant in the semiconductor device **1** according to the embodiment of the present invention, wherein FIG. **8(a)** is a plan view and FIG. **8(b)** is a side view. This calculation example is applied mainly to the cooler **50** in which the end portion of the first header part **54** at the position B-B shown in FIGS. **8(a)** and **8(b)** is in the shape of a letter "I."

FIGS. **9(a)** and **9(b)** are contour diagrams showing a numerically calculated distribution of flow velocities of a coolant in the conventional semiconductor device, wherein FIG. **9(a)** is a plan view and FIG. **9(b)** is a side view. This calculation example is applied mainly to the cooler **500** shown in FIG. **7(a)**.

FIGS. **8(a)** to **9(b)** show the distribution of flow velocities in which the flow rates of the coolant are 10 L/min. The numerical values (0.000 to 1.000) shown in these diagrams indicate the flow velocities (unit: m/s) of the coolants. For comparison, the maximum flow velocity is set at 1.000 m/s for the both coolants.

When comparing the flow velocity distribution of FIGS. **8(a)** and **8(b)** according to the embodiment of the present invention with the conventional one shown in FIGS. **9(a)** and **9(b)**, the semiconductor device **1** according to the embodiment of the present invention has a low flow velocity in the cooling fins **41** at the first header part **54**, and the flow velocity changes slowly. Moreover, a substantially uniform distribution is obtained between downstream-side end portion of the first header part **54** (the position B-B shown in FIGS. **8(a)** and **8(b)**) and the downstream-side end portion of the cooling fins **41** (the position C-C shown in FIGS. **8(a)** and **8(b)**). Therefore, the cooling performance of the cooler **50** is substantially uniform between the coolant inlet **52** and the coolant outlet **53**, leading to a reduction in pressure loss.

For example, as a result of numerically calculating the junction temperature of the power semiconductor chips **31** mounted in the insulating substrates **33-1**, **33-2**, **33-3**, with the length l_w shown in FIG. **5(a)** being set at 15 mm, the length l_o at 1 mm, and the length of the cooling fins **41** at 10 mm, the temperature of the chips mounted in the insulating substrate **33-1** on the coolant inlet **52** side was approximately 134.7° C., and the temperature of the chips mounted in the insulating substrate **33-3** on the coolant outlet **53** side was approximately 136.0° C., the difference being approximately 1.3° C. In addition, the pressure loss was 9.3 kPa. However, as a result of the same calculation with l_w 1 mm and l_o 1 mm shown in FIG. **7(d)**, the difference between the temperatures was approximately 2.7° C. and the pressure loss was 11.1 kPa.

In the prior art, reducing the length of the cooling fins **41** did not evenly cool the plurality of power semiconductor chips **31** disposed in the longitudinal direction, but the semiconductor device **1** according to the embodiment of the

13

present invention can provide the excellent effect of keeping the temperature difference low even after further reducing the length of the cooling fins **41** as short as, for example, to approximately 6 mm.

Furthermore, as a result of another numerical calculation on the conventional semiconductor device shown in FIG. 7(d) where the lengths of l_w and l_o were equal to each other and changed from 1 to 5, 10, and 15 mm, it was found that the temperatures of all of the power semiconductor chips mounted in the insulating substrates **33-1**, **33-2**, **33-3** increased when the length l_w (l_o) was increased from 1 mm to 15 mm, making it impossible to evenly cool the power semiconductor chips.

As described above, in the semiconductor device **1** and the cooler **50** according to the embodiment of the present invention, the cooling unit **51** of the cooler **50** has the first header part **54**, which has at least the bottom surface inclined toward the bottom plane of the cooling fins **41**, and the second header part **55**, which has at least the bottom surface inclined from the end portion of the bottom plane of the cooling fins **41**. Owing to this configuration, the coolant supplied from the coolant inlet **52** flows through the cooling fins **41** from the side plane and bottom plane of the cooling fins **41** on the coolant inlet **52** toward the coolant outlet **53**, and is then discharged from the side plane of the cooling fins **41** to the coolant outlet **53**. As a result, the pressure loss and cooling efficiency in the first header part **54** can be lowered, resulting in cooling the power semiconductor chips **31** of the three insulating substrates **33** substantially evenly and reducing the pressure loss of the cooler **50**, the insulating substrates **33** being disposed in the longitudinal direction of the cooling unit **51**.

It should be noted that the embodiment described above is to illustrate the specific examples of the present invention. Therefore, needless to say, the present invention should not be construed as being limited to the embodiment, and various modifications can be made to the present invention without departing from the gist thereof.

EXPLANATION OF REFERENCE NUMERALS

1 Semiconductor device
30 Semiconductor module
31 Power semiconductor chip
32 Surrounding case
32a, **32b** Opening stepped surface
32c Lid plate
32e Sealing member
32n Nut
33, **33-1**, **33-2**, **33-3** Insulating substrate
34, **34-1**, **34-2**, **34-3** Main terminal
35, **35-1**, **35-2** Power supply terminal
35a Open hole
36, **36-1** to **36-8** Control terminal
37, **37-1** to **37-4** Opening
 Screw seat
 FWD
 $w1$, $w2$, $w3$ Bonding wire
 $r1$, $r2$ Lead terminal
40, **40-1** Heat dissipation base plate
41, **41-1**, **41-2**, **41-3** Cooling fins
50 Cooler
51 Cooling unit
52 Coolant inlet
53 Coolant outlet
54 First header part
55 Second header part

14

The invention claimed is:

1. A semiconductor device comprising:

a semiconductor module having a substrate and a power semiconductor elements;

a heat dissipation base;

cooling fins forming a cluster of at least one of a plurality of pin members or a plurality of blade members, the cluster having a rectangular cuboid contour and provided on a first principal surface of the heat dissipation base;

a cooler fixed to the heat dissipation base and having a cooling unit accommodating the cooling fins therein and a coolant inlet and a coolant outlet formed at respective ends of the cooling unit to face each other in a longitudinal direction;

a first substrate having at least a first one of the power semiconductor elements, the first substrate bonded to a second principal surface of the heat dissipation base at a coolant inlet side such that a position of the first substrate corresponds to a position of the cooling fins; and

a second substrate having at least a second one of the power semiconductor elements, the second substrate bonded to the second principal surface of the heat dissipation base at a coolant outlet side,

wherein the cooling unit includes:

a first header part having at least a first bottom surface that is inclined toward a bottom plane of the cooling fins so that a coolant supplied from the coolant inlet flows from a side plane of the cooling fins and the bottom plane of the cooling fins on the coolant inlet side into the cooling fins and toward the coolant outlet;

a second header part having at least a second bottom surface that is inclined from an end portion of the bottom plane of the cooling fins so that the coolant discharged from the cooling fins flows to the coolant outlet, and

a third bottom surface extending between the first bottom surface and the second bottom surface and parallel to the bottom plane of the cooling fins, wherein an inclination angle of the first bottom surface with respect to the bottom plane of the cooling fins is smaller than an inclination angle of the second bottom surface with respect to the bottom plane of the cooling fins, and

wherein a top portion in which the first bottom surface and the third bottom surface intersect, is located between a lower part of a center of the first substrate and a lower part of an end portion of the first substrate on the coolant outlet side.

2. The semiconductor device according to claim 1, wherein a volume of the first header part is greater than that of the second header part.

3. The semiconductor device according to claim 1, wherein an inner diameter of a pipe connected to the coolant inlet and the coolant outlet is greater than a height of the at least one of the blade members or pin members.

4. The semiconductor device according to claim 1, wherein a side wall of the cooling unit is not located immediately below the first substrate and the second substrate.

5. The semiconductor device according to claim 1, wherein the cooling fins are the pin members, the pin members each having a circular, oval, or polygonal cross-sectional shape, and the pin members are staggered on the heat dissipation base.

15

6. A semiconductor device comprising:
- a semiconductor module having power semiconductor elements;
 - a heat dissipation base;
 - cooling fins forming a cluster of at least one of a plurality of pin members or a plurality of blade members, the cluster having a rectangular cuboid contour and provided on a first principal surface of the heat dissipation base;
 - a cooler fixed to the heat dissipation base and having a cooling unit accommodating the cooling fins therein and a coolant inlet and a coolant outlet formed at respective ends of the cooling unit to face each other in a longitudinal direction;
 - a first substrate having at least a first one of the power semiconductor elements, the first substrate bonded to a second principal surface of the heat dissipation base at a coolant inlet side such that a position of the first substrate corresponds to a position of the cooling fins; and
 - a second substrate having at least a second one of the power semiconductor elements, the second substrate bonded to the second principal surface of the heat dissipation base at a coolant outlet side,
- wherein the cooling unit includes:
- a first header part for supplying a coolant from the coolant inlet toward the cooling fins; and
 - a second header part for discharging the coolant from the cooling fins to the coolant outlet,
 - areas of a side plane of the cluster of the cooling fins and a bottom plane of the cluster of the cooling fins exposed into the first header part are greater than areas of a side plane of the cluster of the cooling fins exposed to the second header part,
 - the areas of the bottom plane of the cooling fins exposed into the first header part are greater than the areas of the side plane of the cooling fins exposed into the first header part,
 - a first bottom surface of the first header part is inclined toward the bottom plane of the cooling fins,
 - a second bottom surface of the second header part is inclined from an end portion of the bottom plane of the cooling fins on the coolant outlet side,
 - a third bottom surface extends between the first bottom surface and the second bottom surface and parallel to the bottom plane of the cooling fins, and
 - a top portion in which the first bottom surface and the third bottom surface intersect is located between a lower part of a center of the first substrate and a lower part of an end portion of the first substrate on the coolant outlet side.

16

7. A cooler for cooling a semiconductor module, comprising:
- a heat dissipation base;
 - at least two substrates bonded co-planar with each other on the heat dissipation base;
 - power semiconductor elements mounted on each of the substrates;
 - cooling fins forming a cluster of at least one of a plurality of pin members or a plurality of blade members, the cluster having a rectangular cuboid contour and provided on the heat dissipation base;
 - a cooling unit accommodating the cooling fins therein; and
 - a coolant inlet and a coolant outlet that are formed at respective ends of the cooling unit to face each other in a longitudinal direction,
- wherein the cooling unit includes:
- a first header part having at least a first bottom surface inclined toward a bottom plane of the cooling fins so that a coolant supplied from the coolant inlet flows from a side plane of the cooling fins and the bottom plane of the cooling fins on the coolant inlet side into the cooling fins and toward the coolant outlet; and
 - a second header part having at least a second bottom surface inclined from an end portion of the bottom plane of the cooling fins so that the coolant discharged from the cooling fins flows to the coolant outlet, and
- the cooler unit is used by being fixed to the heat dissipation base,
- the at least two substrates include a first substrate disposed on the coolant inlet side and a second substrate disposed on the coolant outlet side so as to be co-planar to the first substrate,
- the first bottom surface is inclined toward the bottom plane of the cooling fins corresponding to a region between a center of the first substrate and an end portion of the first substrate on the coolant outlet side,
- a third bottom surface extends between the first bottom surface and the second bottom surface and parallel to the bottom plane of the cooling fins, and
- a top portion in which the first bottom surface and the third bottom surface intersect is located between a lower part of a center of the first substrate and a lower part of an end portion of the first substrate on the coolant outlet side.
8. The cooler according to claim 7, wherein the first header part and the second header part are formed such that an inclination angle of the first bottom surface with respect to the bottom plane of the cooling fins is smaller than an inclination angle of the second bottom surface.

* * * * *